·	Application No.	Applicant(s)	
Notice of Allowability	09/455,991	OHTANI ET AL.	
	Examiner	Art Unit	
	José R. Díaz	2815	
The MAILING DATE of this communication appear All claims being allowable, PROSECUTION ON THE MERITS IS (herewith (or previously mailed), a Notice of Allowance (PTOL-85) NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RIGOT THE Office or upon petition by the applicant. See 37 CFR 1.313	OR REMAINS) CLOSED in this apport or other appropriate communication GHTS. This application is subject to	olication. If not include will be mailed in due	ed course. THIS
1. X This communication is responsive to 6/17/05.			
2. X The allowed claim(s) is/are 6-12,14-16,18,20,21 and 23-79.			
3. X The drawings filed on <u>06 December 1999</u> are accepted by the Examiner.			
4.	been received. been received in Application No. Obscuments have been received in this suments of this application. Itted. Note the attached EXAMINER's reason(s) why the oath or declarate to be submitted. It be submitted. It is a summitted in the comment or in the Comment or in the Comment or in the Comment or in the Comment of BIOLOGICAL MATERIAL resit of BIOLOGICAL MATERIAL residence.	complying with the recomplying and the recomplying in the front (not the d).	quirements
Attachment(s) 1. ☐ Notice of References Cited (PTO-892) 2. ☐ Notice of Draftperson's Patent Drawing Review (PTO-948) 3. ☐ Information Disclosure Statements (PTO-1449 or PTO/SB/0 Paper No./Mail Date 12 02 10 02 4. ☐ Examiner's Comment Regarding Requirement for Deposit of Biological Material	5. ☐ Notice of Informal P 6. ☐ Interview Summary Paper No./Mail Dat 8), 7. ☐ Examiner's Amendr 8. ☑ Examiner's Stateme 9. ☐ Other	(PTO-413), te ment/Comment	ŕ

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REASONS FOR ALLOWANCE

The following is an examiner's statement of reasons for allowance: the prior art fails to teach, disclose, or suggest, either alone or in combination, the steps of crystallizing an amorphous semiconductor film from a first element added region and a second metal element added region in parallel to the substrate to form a first crystalline portion and a second crystalline portion, respectively; patterning the first crystalline portion to form an active semiconductor island while the second crystalline portion is not used to form any active semiconductor island, as instantly claimed, and in combination with the additional method steps.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

Correspondence

Any inquiry concerning this communication or earlier communications from the examiner should be directed to José R. Díaz whose telephone number is (571) 272-1727. The examiner can normally be reached on Monday through Thursday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Tom Thomas can be reached on (571) 272-1664. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

José R. Díaz Examiner Art Unit 2815

> JEROME JACKSON PRIMARY EXAMINER